



# STTA3006P/PI STTA6006TV1/2

## TURBOSWITCH™ ULTRA-FAST HIGH VOLTAGE DIODE

### MAIN PRODUCT CHARACTERISTICS

I <sub>F(AV)</sub>	30A / 2 x 30A
V <sub>RRM</sub>	600V
t <sub>rr</sub> (typ)	35ns
V <sub>F</sub> (max)	1.5V

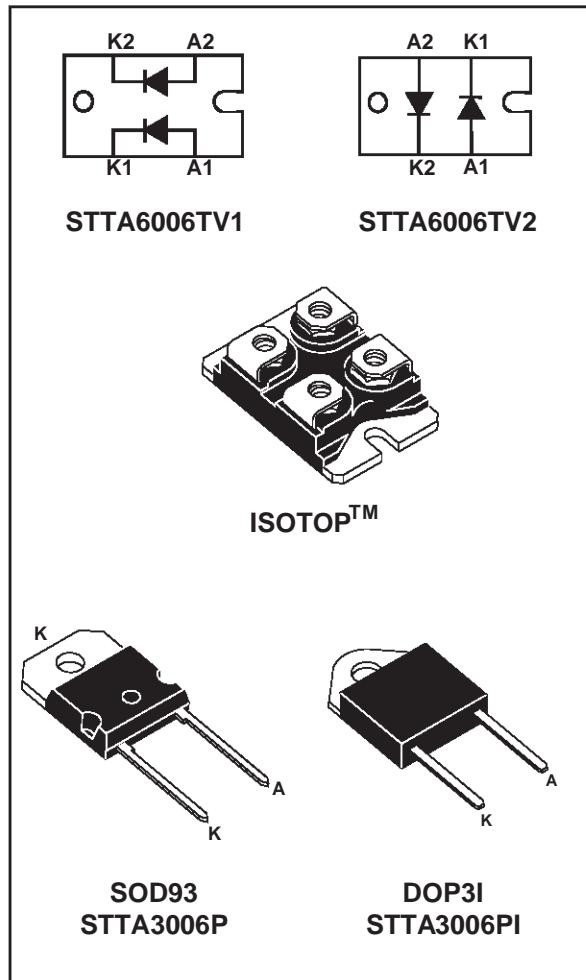
### FEATURES AND BENEFITS

- SPECIFIC TO "FREEWHEEL MODE" OPERATIONS: FREEWHEEL OR BOOSTER DIODE
- ULTRA-FAST AND SOFT RECOVERY
- VERY LOW OVERALL POWER LOSSES IN BOTH THE DIODE AND THE COMPANION TRANSISTOR
- HIGH FREQUENCY OPERATIONS
- INSULATED PACKAGE : ISOTOP & DOP3I  
Electrical insulation : 2500V<sub>RMS</sub>  
Capacitance < 12 pF (DOP3I)  
Capacitance < 45 pF (ISOTOP)

### DESCRIPTION

The TURBOSWITCH is a very high performance series of ultra-fast high voltage power diodes from 600V to 1200V.

TURBOSWITCH family, drastically cuts losses in both the diode and the associated switching IGBT or MOSFET in all "freewheel mode" operations and is particularly suitable and efficient in motor control freewheel applications and in booster diode applications in power factor control circuitries. Packaged either in ISOTOP, DOP3I or SOD93 these 600V devices are particularly intended for use on 240V domestic mains.



### ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter		Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage		600	V
V <sub>RSM</sub>	Non repetitive peak reverse voltage		600	V
I <sub>F(RMS)</sub>	RMS forward current		50	A
I <sub>FRM</sub>	Repetitive peak forward current	tp=5μs F=5kHz square	300	A
I <sub>FSM</sub>	Surge non repetitive forward current	tp=10 ms sinusoidal	230	A
T <sub>j</sub>	Maximum operating junction temperature		150	°C
T <sub>stg</sub>	Storage temperature range		-65 to 150	°C

TM : TURBOSWITCH is a trademark of STMicroelectronics

## STTA6006TV1/2/ STTA3006P/PI

### THERMAL AND POWER DATA (Per diode)

Symbol	Parameter	Test conditions		Value	Unit
$R_{th(j-c)}$	Junction to case thermal resistance	ISOTOP	Per diode	1.4	$^{\circ}\text{C}/\text{W}$
			Total	0.75	
		DOP3I		1.8	
		SOD93		1.2	
$R_{th(c)}$		ISOTOP	Coupling	0.1	$^{\circ}\text{C}/\text{W}$
$P_1$	Conduction power dissipation $I_F(\text{AV}) = 30\text{A}$ $\delta = 0.5$	ISOTOP	$T_c = 74^{\circ}\text{C}$	54	W
		DOP3I	$T_c = 52^{\circ}\text{C}$		
		SOD93	$T_c = 85^{\circ}\text{C}$		
$P_{\max}$	Total power dissipation $P_{\max} = P_1 + P_3$ ( $P_3 = 10\% P_1$ )	ISOTOP	$T_c = 66^{\circ}\text{C}$	60	W
		DOP3I	$T_c = 42^{\circ}\text{C}$		
		SOD93	$T_c = 78^{\circ}\text{C}$		

### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions		Min	Typ	Max	Unit
$V_F$ *	Forward voltage drop	$I_F = 30\text{A}$	$T_j = 25^{\circ}\text{C}$			1.75	V
			$T_j = 125^{\circ}\text{C}$		1.25	1.5	V
$I_R$ **	Reverse leakage current	$V_R = 0.8 \times V_{RRM}$	$T_j = 25^{\circ}\text{C}$			150	$\mu\text{A}$
			$T_j = 125^{\circ}\text{C}$		3	8	mA
$V_{to}$	Threshold voltage	$I_p < 3.I_{AV}$	$T_j = 125^{\circ}\text{C}$			1.15	V
$r_d$	Dynamic resistance					11	$\text{m}\Omega$

Test pulses : \*  $t_p = 380 \mu\text{s}$ ,  $\delta < 2\%$

\*\*  $t_p = 5 \text{ ms}$ ,  $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation :

$$P = V_{to} \times I_{F(\text{AV})} + r_d \times I_F^2(\text{RMS})$$

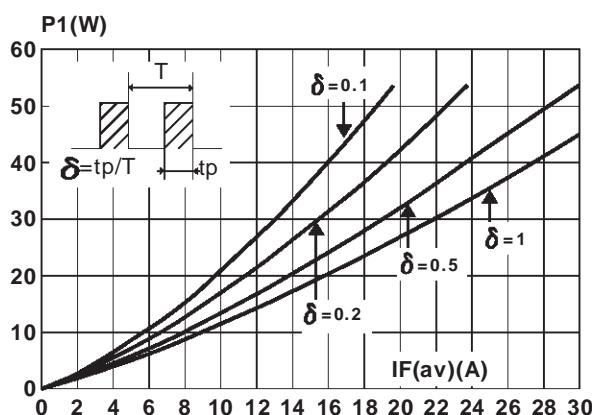
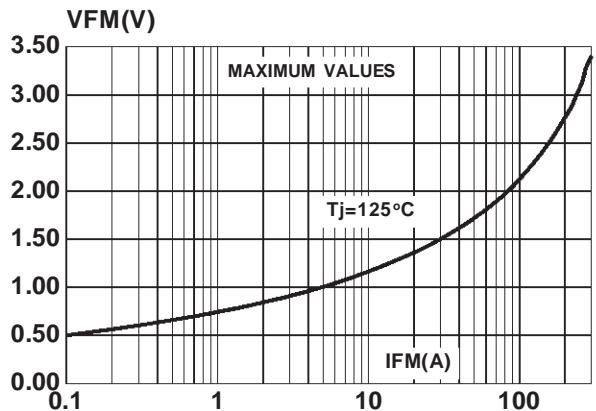
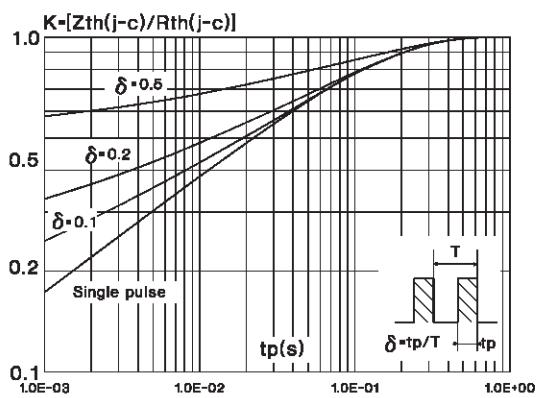
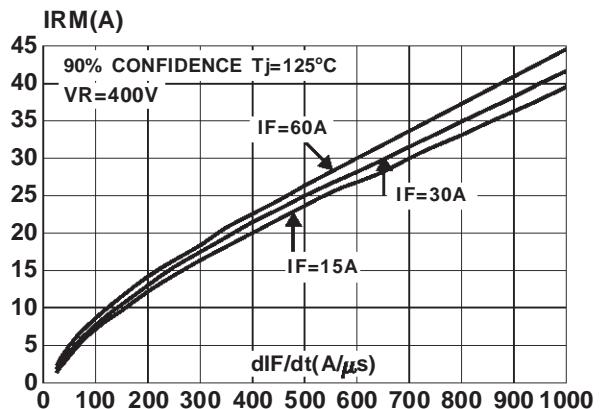
### DYNAMIC ELECTRICAL CHARACTERISTICS

#### TURN-OFF SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
$t_{rr}$	Reverse recovery time	$T_j = 25^{\circ}\text{C}$ $I_F = 0.5 \text{ A}$ $I_R = 1 \text{ A}$ $I_{rr} = 0.25 \text{ A}$ $I_F = 1 \text{ A}$ $dI_F/dt = -50 \text{ A}/\mu\text{s}$ $V_R = 30 \text{ V}$		35	65	ns
$I_{RM}$	Maximum reverse recovery current	$T_j = 125^{\circ}\text{C}$ $V_R = 400 \text{ V}$ $I_F = 30 \text{ A}$ $dI_F/dt = -240 \text{ A}/\mu\text{s}$ $dI_F/dt = -500 \text{ A}/\mu\text{s}$		20	19	A
S factor	Softness factor	$T_j = 125^{\circ}\text{C}$ $V_R = 400 \text{ V}$ $I_F = 30 \text{ A}$ $dI_F/dt = -500 \text{ A}/\mu\text{s}$		0.40		-

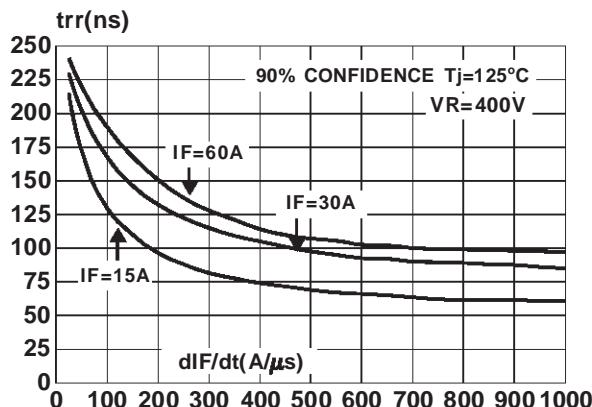
## TURN-ON SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
$t_{fr}$	Forward recovery time	$T_j = 25^\circ\text{C}$ $I_F = 30\text{A}$ , $dI_F/dt = 240 \text{ A}/\mu\text{s}$ measured at, $1.1 \times V_{F\max}$			600	ns
$V_{Fp}$	Peak forward voltage	$T_j = 25^\circ\text{C}$ $I_F = 30\text{A}$ , $dI_F/dt = 240 \text{ A}/\mu\text{s}$			12	V

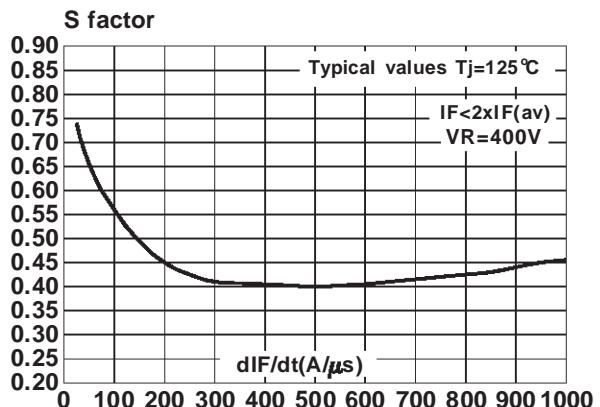
**Fig. 1:** Conduction losses versus average current.**Fig. 2:** Forward voltage drop versus forward current.**Fig. 3:** Relative variation of thermal transient impedance junction to case versus pulse duration.**Fig. 4:** Peak reverse recovery current versus  $dI_F/dt$ .

## STTA6006TV1/2/ STTA3006P/PI

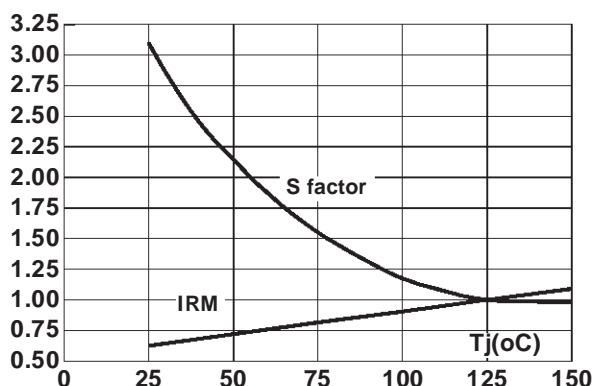
**Fig. 5:** Reverse recovery time versus  $dI_F/dt$ .



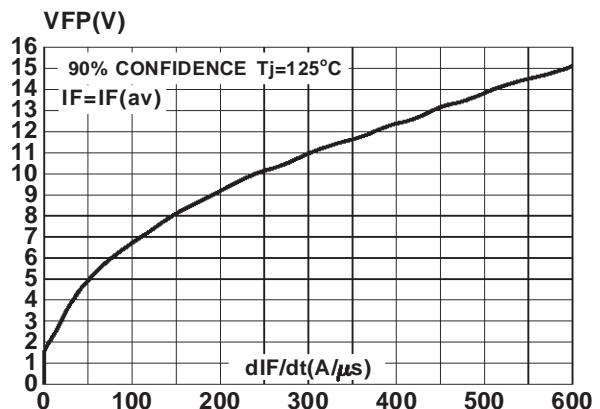
**Fig. 6:** Softness factor (tb/ta) versus  $dI_F/dt$ .



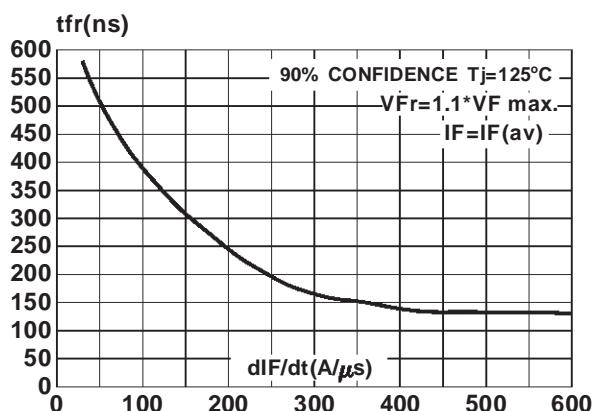
**Fig. 7:** Relative variation of dynamic parameters versus junction temperature (reference  $T_j=125^\circ\text{C}$ ).



**Fig. 8:** Transient peak forward voltage versus  $dI_F/dt$ .



**Fig. 9:** Forward recovery time versus  $dI_F/dt$ .



## APPLICATION DATA

The TURBOSWITCH is especially designed to provide the lowest overall power losses in any "FREEWHEEL Mode" application (Fig.A) considering both the diode and the companion

transistor, thus optimizing the overall performance in the end application.  
The way of calculating the power losses is given below:

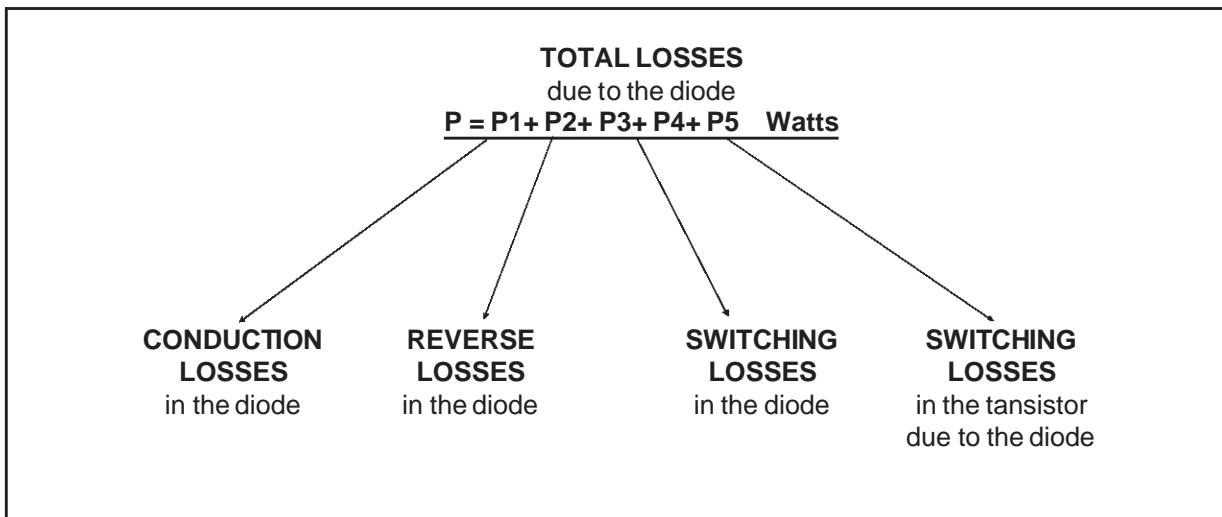
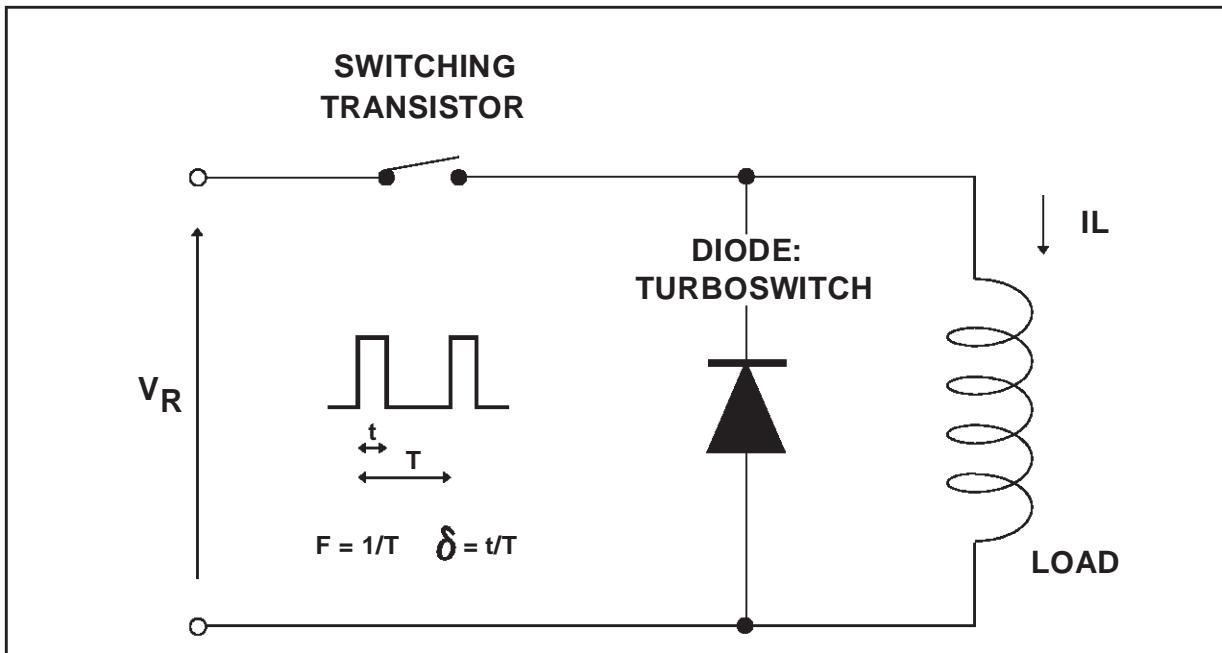
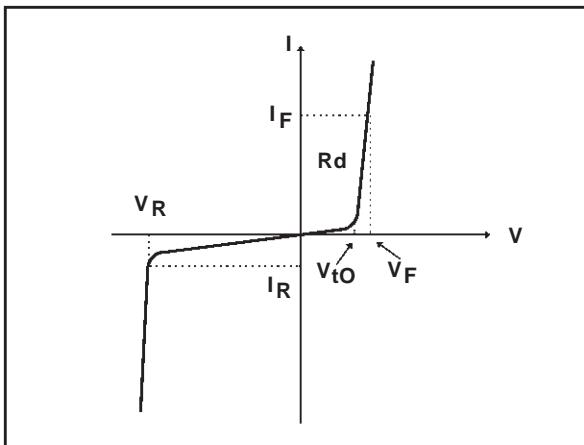


Fig. A : "FREEWHEEL" MODE.



APPLICATION DATA (Cont'd)

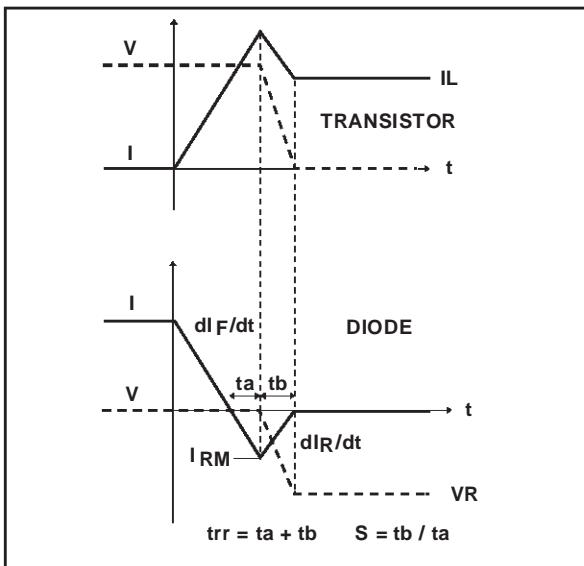
**Fig. B:** STATIC CHARACTERISTICS



**Conduction losses:**  
 $P_1 = V_{tO} \cdot I_F(AV) + R_d \cdot I_F^2(RMS)$

**Reverse losses:**  
 $P_2 = V_R \cdot I_R \cdot (1 - \delta)$

**Fig. C:** TURN-OFF CHARACTERISTICS



**Turn-on losses:**  
(in the transistor, due to the diode)

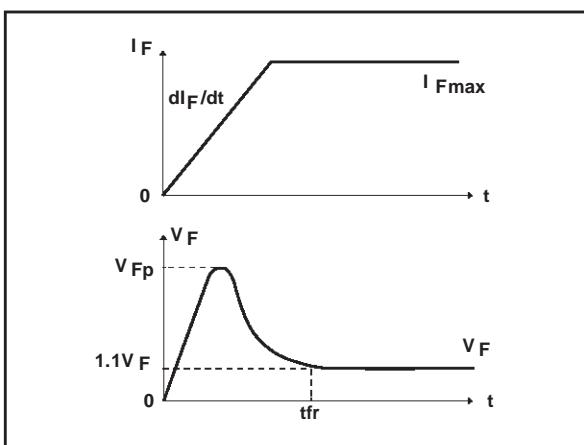
$$P_5 = \frac{V_R \times I_{RM}^2 \times (3 + 2 \times S) \times F}{6 \times dI/dt} + \frac{V_R \times I_{RM} \times I_L \times (S+2) \times F}{2 \times dI/dt}$$

**Turn-off losses (in the diode):**

$$P_3 = \frac{V_R \times I_{RM}^2 \times S \times F}{6 \times dI/dt}$$

$P_3$  and  $P_5$  are suitable for power MOSFET and IGBT

**Fig. D:** TURN-ON CHARACTERISTICS



**Turn-on losses:**  
 $P_4 = 0.4 (V_{FP} - V_F) \cdot I_{Fmax} \cdot tfr \cdot F$

**PACKAGE MECHANICAL DATA**  
 ISOTOP

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	11.80		12.20	0.465		0.480
A1	8.90		9.10	0.350		0.358
B	7.8		8.20	0.307		0.323
C	0.75		0.85	0.030		0.033
C2	1.95		2.05	0.077		0.081
D	37.80		38.20	1.488		1.504
D1	31.50		31.70	1.240		1.248
E	25.15		25.50	0.990		1.004
E1	23.85		24.15	0.939		0.951
E2		24.80			0.976	
G	14.90		15.10	0.587		0.594
G1	12.60		12.80	0.496		0.504
G2	3.50		4.30	0.138		0.169
F	4.10		4.30	0.161		0.169
F1	4.60		5.00	0.181		0.197
P	4.00		4.30	0.157		0.69
P1	4.00		4.40	0.157		0.173
S	30.10		30.30	1.185		1.193

Cooling method : by conduction (C)

**STTA6006TV1/2/ STTA3006P/PI****PACKAGE MECHANICAL DATA  
SOD93**

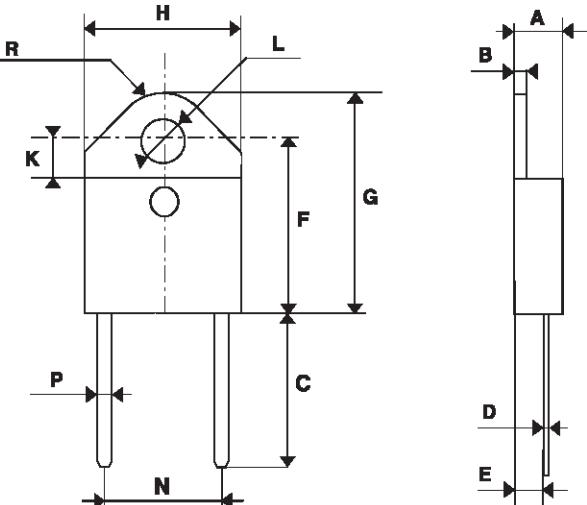
REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.70		4.90	0.185		0.193
C	1.17		1.37	0.046		0.054
D		2.50			0.098	
D1		1.27			0.050	
E	0.50		0.78	0.020		0.031
F	1.10		1.30	0.043		0.051
F3		1.75			0.069	
G	10.80		11.10	0.425		0.437
H	14.70		15.20	0.578		0.598
L			12.20			0.480
L2			16.20			0.638
L3		18.0			0.709	
L5	3.95		4.15	0.156		0.163
L6		31.00			1.220	
O	4.00		4.10	0.157		0.161

Cooling method : by conduction (C)

Recommended torque value : 0.8 m.N

Maximum torque value : 1m.N

**PACKAGE MECHANICAL DATA**  
DOP3I



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	1.45	1.55	0.057	0.061
C	14.35	15.60	0.565	0.614
D	0.5	0.7	0.020	0.028
E	2.7	2.9	0.106	0.114
F	15.8	16.5	0.622	0.650
G	20.4	21.1	0.815	0.831
H	15.1	15.5	0.594	0.610
K	3.4	3.65	0.134	0.144
L	4.08	4.17	0.161	0.164
N	10.8	11.3	0.425	0.444
P	1.20	1.40	0.047	0.055
R	4.60 typ.		0.181 typ.	

Cooling method : by conduction (C)

Recommended torque value : 0.8 m.N

Maximum torque value : 1m.N

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTA6006P	STTA6006P	SOD93	3.79g	30	Tube
STTA6006PI	STTA6006PI	DOP3I	4.52g	30	Tube
STTA6006TV1	STTA6006TV1	ISOTOP	27g	10	Tube
STTA6006TV2	STTA6006TV2	ISOTOP	without screws	10	Tube

- Epoxy meets UL94,V0

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